PUBLICATIONS, PATENTS, AND PRESENTATIONS
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REFEREED JOURNAL PAPERS


Y. Vygranenko, E. Fathi, A. Sazonov, M. Vieira, A. Nathan, “Nanocrystalline p-layer for a-Si:H p–

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PATENTS FILED/AWARDED


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Nanocrystalline silicon for displays and photovoltaics, UK-Korea Nano Forum, Seoul, Korea, Aug 20, 2010

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